



ENS220

Premium accuracy barometric pressure
and temperature sensor for activity
tracking and indoor navigation /
localization

ENS220 datasheet

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The ENS220 is an ultra-low-power, high-accuracy barometric pressure and temperature sensor. It comes in the smallest size LGA package with digital I²C and SPI interfaces. This enables new use cases in activity tracking, indoor navigation/localization, fall- and liquid-level detection.

The capacitive pressure sensor of the ENS220 is integrated on a CMOS ASIC. This single die solution not only allows small form factor packages with excellent immunity to changes in environmental conditions, but also achieves ultra-low current consumption due to the capacitive read-out. High intrinsic pressure sensitivity combined with an ultra-low noise 24-bit ADC converter results in unprecedented low pressure noise. The integrated temperature sensor matches the performance of dedicated temperature measurement devices. It ensures a stable, temperature compensated pressure output with a fast response time. The highly accurate pressure reading, and the short conversion time make the ENS220 perfect for height measurements with a high output data rate and high bandwidth.

Key Features & Benefits

Premium **absolute accuracy**: ± 0.5 hPa

Relative accuracy: ± 0.025 hPa (equiv. to ± 20 cm) allows ultra-fine differential pressure measurements for reliable **centimeter resolution positioning**

Lowest power: average supply current of $0.1 \mu\text{A}$ at idle, $0.8 \mu\text{A}$ when sampling at $1/60$ Hz, ensures **long battery life** even at high sampling rates

Ultra-low noise of 0.1 Pa rms (≈ 1 cm) at 2 Hz sample rate

User-configurable sample rate up to 1 kHz (0.9 Pa rms)

Temperature accuracy of 0.2 K with 8 mK resolution

Fully digital interface with best-of-breed form factor, which perfectly integrates into **space-constraint designs**, e.g., mobiles, wearables, hearables

Interrupt on multiple conditions including **pressure thresholds** for ultra-low power applications

Applications

- Mobile/Wearables: activity tracking, indoor localization/navigation, fall detection
- Gaming, AR/VR, Drones: height tracking
- Appliances/HVAC: filter clogging detection
- White goods: liquid level detection
- Medical: blood pressure measurement
- Accurate temperature meter for gasses and surfaces

Properties

- Small $2.0 \times 2.0 \times 0.75$ mm³ LGA package
- P operating range from 300 to 1200 hPa
- T operating range from -40 to $+85$ °C
- Power supply range from 1.62 V to 1.98 V
- Standard, fast, and high speed I²C and SPI interface
- T&R packaged, reflow solderable.
- MSL1 compliant

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1 Quick Start

A typical application circuit for ENS220 is shown on the left-hand side of Figure 1. After reaching the minimal supply voltage and allowing for the maximal power-up time of 1 ms the sensor is ready for I²C communication. The quickest way to measure pressure and temperature is pseudo-coded in Figure 1. The conversion formulae given in equations in Table 5 and Table 6 are used to translate the digital signals into absolute pressure and temperature readings.

More application examples can be found in chapter 9.

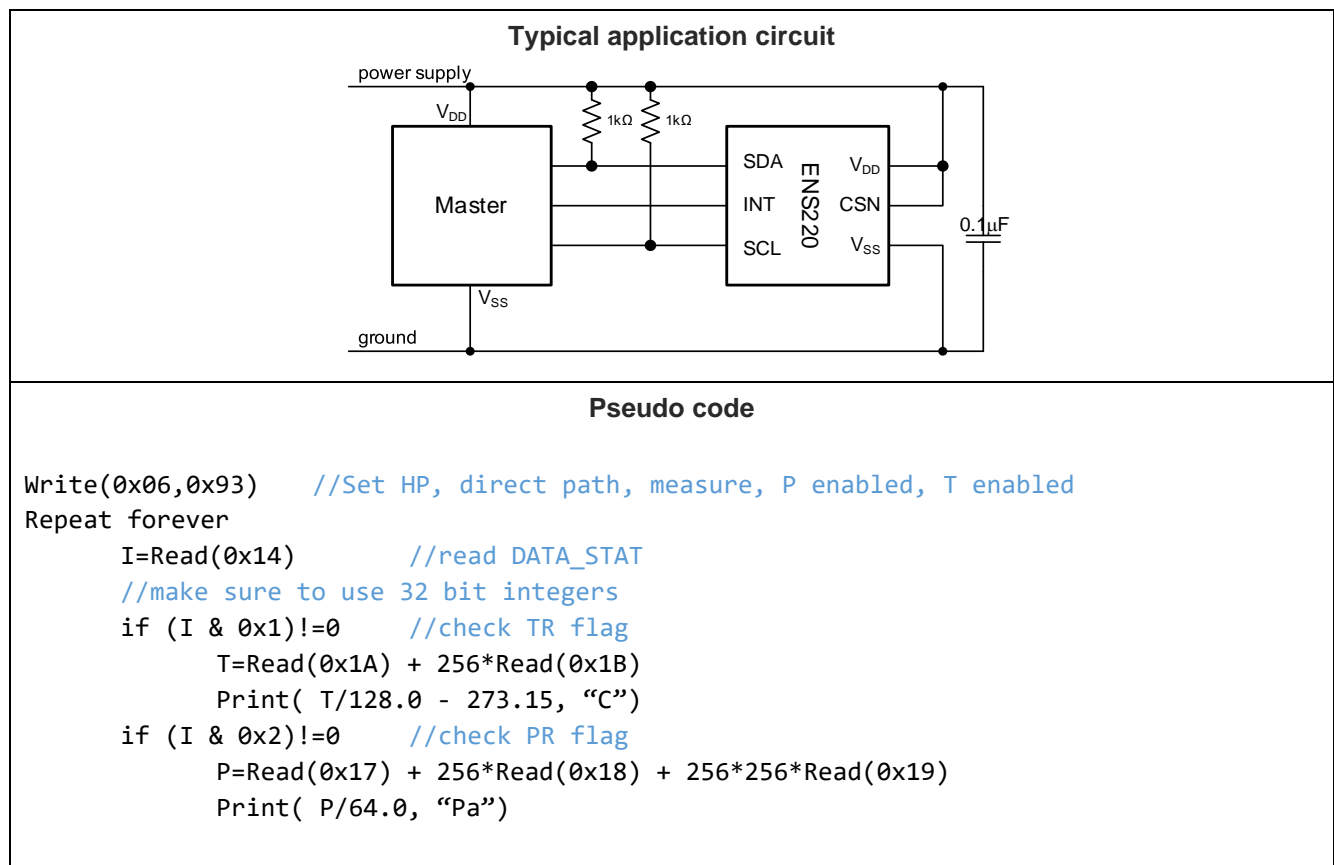


Figure 1: Typical application circuit (top) and pseudo code (bottom) for easy starting. For details on the sensor configuration see section 6.



Find code resources and embedded drivers on: <https://github.com/ScioSense>

2 Pin assignment

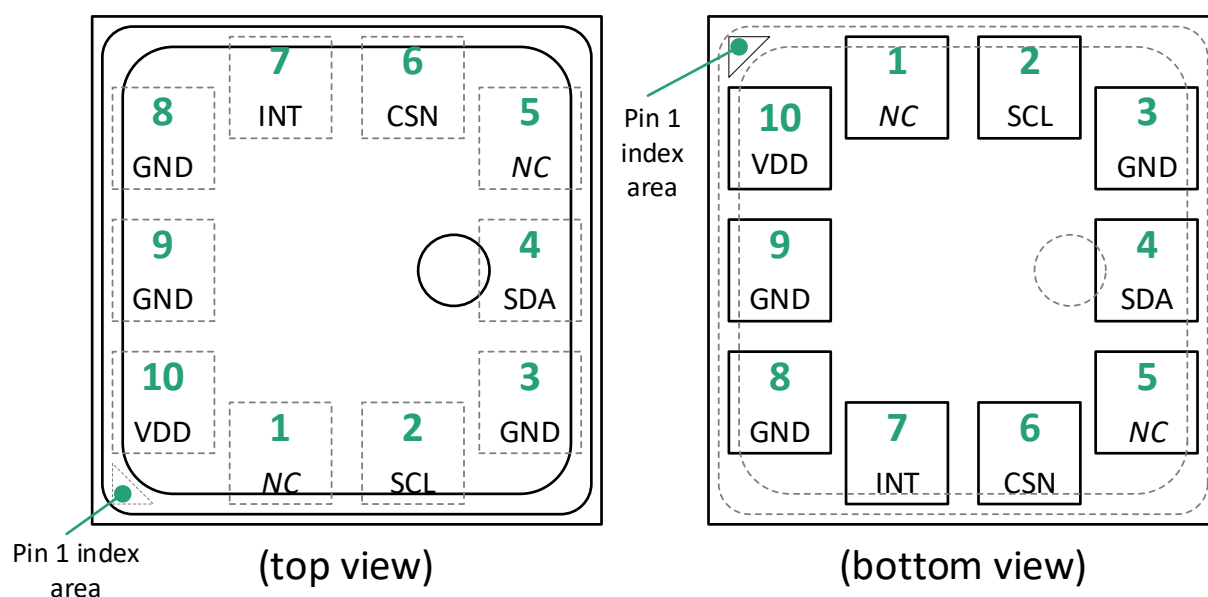


Figure 2: Pin diagram (NC = not connected)

Also see sections 9.1 “I2C operation circuitry” and 9.2 “SPI operation circuitry” for wiring.

Table 1: Pin description

| Pin | Pin Name | Pin Type | Description |
|---------|------------------------|----------------|--|
| 1, 5 | NC | unconnected | Unconnected pins. These are isolated from each other pin. |
| 2 | SCLK / SCL | Input | SPI Serial Clock / I ² C Bus Serial Clock Input |
| 3, 8, 9 | GND (V _{SS}) | Supply | Ground Supply Voltage |
| 4 | MOSI / SDA | Input / Output | SPI Master Output Slave Input / I ² C Bus Bi-Directional Data |
| 6 | CSn | Input | SPI Interface Select (CSn low -> SPI / CSn high -> I ² C) |
| 7 | MISO / INTn | Output | SPI Master Input Slave Output / Interrupt to Host |
| 10 | V _{DD} | Supply | Supply Voltage |

3 Pressure and temperature specifications

Default conditions of 25 °C, 50 % RH, without MSL1 pre-conditioning, default periodic measurement apply to values in the table below, unless otherwise stated.

Table 2: Pressure and temperature specifications

| Symbol | Parameter | Min | Typ | Max | Unit | Comments |
|---------------------|--|-----|-------|------|---------|----------------------------------|
| Pressure | | | | | | |
| P _{RANGE} | Pressure operating range | 300 | | 1200 | hPa | |
| P _{ACC} | Absolute pressure accuracy 500-1100hPa -5 °C ... 55 °C | | ±0.5 | | hPa | |
| | Absolute pressure accuracy 500-1100 hPa, -20 °C ... 70 °C | | ±1 | | hPa | |
| | Absolute pressure accuracy 300-1200 hPa, -40 °C ... 85 °C | | ±3 | | hPa | |
| P _{REL} | Relative accuracy P step of 10hPa in 600..1100 hPa and/or T change -5..55 °C | | 2.5 | | Pa | |
| P _{RES} | Pressure resolution (1 LSB) | | 1/64 | | Pa | |
| P _{DRIFT} | Long term stability ¹ | | ±10 | | Pa/year | |
| P _{SOLDER} | Solder shift (conditions in Figure 31) | | ±1 | | hPa | |
| T _{SENS} | Temperature sensitivity 500-1100 hPa, 25 °C ... 45 °C | | 0.5 | | Pa/K | |
| P _{NOISE} | Pressure noise, 4 ms conversion, no oversampling, 1000 hPa, 25 °C | | 0.85 | 1.25 | Pa rms | (ca. 50 Hz ODR for PT-rate=1) |
| Temperature | | | | | | |
| T _{RANGE} | Temperature operating range | -40 | | 85 | °C | |
| T _{ACC} | Temperature accuracy between 0 °C and 70 °C | | | 0.2 | °C | |
| | Temperature accuracy between -40 °C and 85 °C | | | 0.5 | °C | |
| T _{RES} | Temperature resolution | | 1/128 | | K | |

¹ Average over lifetime, based on temperature-accelerated measurements.

4 Electrical characteristics

The following figure details the electrical characteristics of the ENS220. All limits are guaranteed. The parameters with min and max values are guaranteed with production tests or SQC (Statistical Quality Control) methods.

Table 3: Electrical characteristics

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|----------------------|---|--|-----------|------|------|----------|
| V _{DD} | Positive supply | | 1.71 | 1.8 | 1.98 | V |
| TEMP _{RNG} | Operating temperature range | | -40 | | 85 | °C |
| I _{I_ULP} | Current consumption in idle state with HP activated | VDD=1.8 V, 35 °C | | 105 | | nA |
| | | VDD=1.98 V, 85 °C | | 1600 | | nA |
| I _{I_LP} | Current consumption in idle state with HP deactivated | | | 40 | | uA |
| I _C | Current consumption during T, P conversion | OVP=128, OVT=128, continuous mode | | 75 | | uA |
| ODR | Sampling rate | | | | 970 | 1/s = Hz |
| T _{PUP} | Power up time | | | | 1 | ms |
| T _{VddTr} | VDD rise time at power on | | | | 10 | ms |
| T _{stbyAcc} | Stand-by time accuracy | | | | 20 | |
| T _{CONV_T} | Temperature Conversion time | OVT = 1, T = 25 °C | | 4 | | |
| T _{CONV_P} | Pressure Conversion time | OVP = 1, CV_time = 1, Toff = 1 (no Temp. mmnt) | | 1 | | |
| V _{IH} | High-level input voltage | | VDD - 0.5 | | | |
| V _{IL} | Low-level input voltage | | | | | |

| | | | | | | |
|----------|---------------------------|--|--|--|--|--|
| V_{OH} | High-level output voltage | | | | | |
| V_{OL} | Low-level output voltage | | | | | |

At power on the supply voltage (VDD) must rise within 10 ms (T_{VddTr}) to the minimum supply voltage otherwise the internal reset may malfunction.

5 Absolute maximum ratings

Table 4: Absolute Maximum Ratings

| Symbol | Parameter | Min | Max | Units | Comments |
|----------------------------------|-----------------------------------|--------|----------------------|-------|------------------------------------|
| Electrical Parameters | | | | | |
| V _{DD} | Supply Voltage | -0.3 | 2.17 | V | |
| V _{DDIO} | Interface I/O voltage | -0.3 | V _{DD} +0.3 | V | |
| I _{SCR} | Input Current (latch-up immunity) | - 50 | 50 | mA | JESD78C |
| Electrostatic Discharge | | | | | |
| ESD _{HBM} | Electrostatic Discharge HBM | ± 2000 | | V | JS-001-2014 |
| ESD _{CDM} | Electrostatic Discharge CDM | ± 500 | | V | JESD22-C101E |
| Operating and Storage Conditions | | | | | |
| T _{STRG} | Storage Temperature | -40 | 85 | °C | |
| RH _{STRG} | Storage Relative Humidity | 10 | 90 | % | Non-condensing |
| T _{AMB} ² | Operating Ambient Temperature | -40 | 85 | °C | |
| RH _{AMB} | Operating Ambient Rel. Humidity | 5 | 95 | % | Non-condensing |
| P _{MAX} | Survival pressure | | 5000 | hPa | |
| T _{lifetime} | Sensor lifetime | 10 | | years | Under typical operating conditions |

Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only. Functional operation of the device at these or any other conditions beyond those indicated under Electrical Characteristics is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability and lifetime.

Note: The ENS220 is not designed for use in safety-critical or life-protecting applications.

² The ENS220 is electrically operable in this range, however its pressure sensing performance might vary.

6 Functional description

The ENS220 integrates an absolute pressure sensor, a temperature sensor and an ASIC which performs A/D conversions and provides the pressure and temperature data through a digital interface.

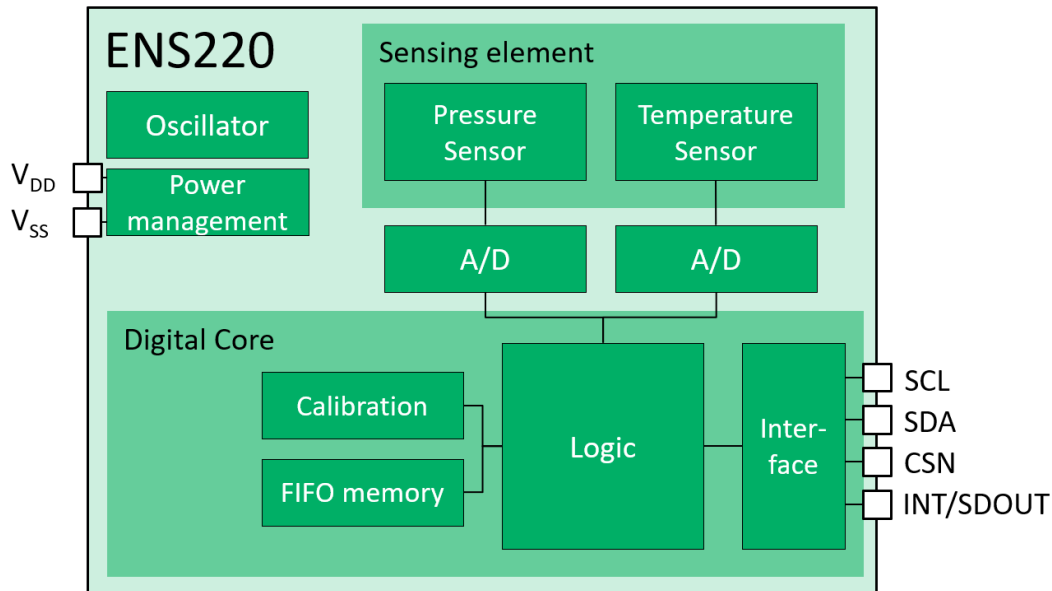


Figure 3: Block diagram of the ENS220

The ENS220 is a sensor capable of providing fast, accurate and temperature measurements at low current consumption. To meet the requirements of different use cases the ENS220 offers very high configuration flexibility.

The configurable features are:

- Operating mode
 - o Continuous
 - o Pulsed
 - o Single Shot
- Pressure measurement precision (conversion time and oversampling) and rate
- Temperature measurement precision (oversampling) and rate
- Ultra-low power mode
- FIFO
- Interrupt behavior
 - o New measurement available
 - o FIFO at watermark level
 - o FIFO full
 - o High resolution pressure threshold
 - o No interrupt
- Moving average

6.1 Measurement modes

The sensor starts powering-up after reaching the power-up threshold voltage $V_{DD, Min} = 1.62\text{ V}$. The sensor enters default the idle mode, in which no measurements are performed, and the sensor configuration can be chosen.

By switching the [START](#) bit to 1, the sensor starts measuring pressure and temperature. The ENS220 can be operated in three measurement modes, which can be selected with the value of [STBY_T](#) (see also Figure 4):

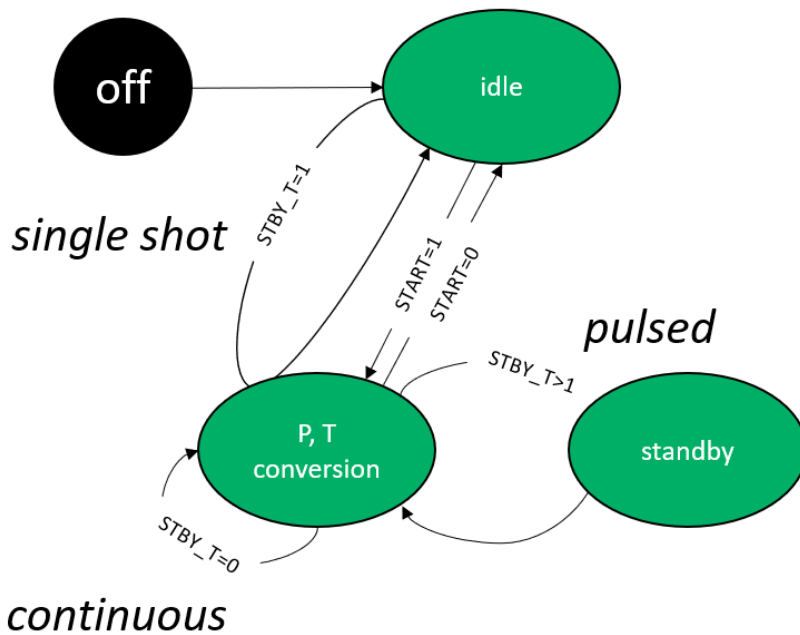


Figure 4: Simplified schematic of measurement modes

- If [STBY_T](#)=0 the device performs **continuous** measurements (temperature and pressure).
- If [STBY_T](#)>1 the device alternates a measurement phase and a standby phase (**pulsed** operation)
- If [STBY_T](#)=1 the device performs a **single** measurement (temperature and pressure) and goes back into idle mode.

The length of the standby phase can be selected from 10 ms to 600 s by writing on [STBY_T](#). A timing diagram of pulsed operation is shown below in Figure 5.

6.2 PT-Rate

In default configuration (see default values in register table), the device performs one pressure measurement followed by a temperature measurement. The ratio between pressure and temperature measurements can be altered by selecting a pressure/temperature rate by writing on [PT_RATE](#). The value varies from 1 to 256. The device will perform a new temperature measurement once every [PT_RATE](#) pressure measurements (see Figure 5).

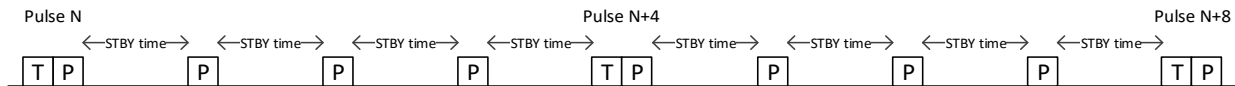


Figure 5: Effect of $PT_RATE=1$ (meaning P/T rate is 4)

$MEAS_P$ and $MEAS_T$ determine whether pressure or temperature measurements take place. If only temperature or only pressure is enabled, PT_RATE has no effect.

The ENS220 uses the temperature value to compensate the pressure output. It is therefore advisable to take regular temperature measurements (at least once per second) to correct temperature fluctuations. For fast temperature transients the temperature measurement should be performed more often to avoid errors in the temperature compensation. The exact requirements for temperature update rate depend on the use case and the physical properties of the soldering substrate and should be evaluated by the user (see also use case examples in chapter 9).

If only pressure measurements are enabled ($MEAS_P=0$), the device will begin with a temperature measurement, then it will continue measuring only pressure (see also Figure 8 in section 6.5).

6.3 Readout

6.3.1 Absolute Pressure

The pressure value is a 24 bit unsigned integer and is available in the sensor readout registers $PRESS_OUT$ and $PRESS_OUT_F$.

The $PRESS_OUT$ value is already calibrated, linearized, and temperature-compensated. It requires a division by 64 to achieve a pressure reading in Pa:

Table 5: Pressure conversion formula

| Pascal |
|----------------------------------|
| $P/[Pa] = \frac{PRESS_OUT}{64}$ |

6.3.2 Temperature

The temperature value is a 16-bit unsigned integer and is available in the sensor readout registers $TEMP_OUT$. Temperature can be calculated as:

Table 6: Temperature conversion formulas

| Celsius | Kelvin |
|--|-----------------------------------|
| $T_c/[^{\circ}C] = \frac{TEMP_OUT}{128} - 273.15$ | $T_K/[K] = \frac{TEMP_OUT}{128}$ |

6.4 Ultra low power mode

Power consumption can be reduced at the expense of some functionality.

If the **HP** bit is 0 (see [MODE_CFG](#)), the power consumption in idle and standby state is low (current draw is I_{I_ULP}) and only the following registers are accessible via SPI/I²C: [MODE_CFG](#), [PART_ID](#), [DATA_STAT](#), [FIFO_STAT](#), [PRESS_OUT](#), [TEMP_OUT](#), [INT_STAT](#).

The use of this feature is recommended for every measurement mode except continuous mode.

By setting **HP** to 1, the power consumption increases to I_{I_LP} and all registers become available.

6.5 Precision and oversampling rate

6.5.1 Absolute Pressure

The precision of the pressure output can be optimized by adjusting the conversion time and oversampling rate.

The ENS220 has a default conversion time t_p of 2 ms for pressure conversion. The conversion time can be selected via [P_CONV](#) to 1 ms, 2 ms or 4 ms. The first measurement after ADC power-up (i.e., after exiting standby mode or after a temperature measurement) requires 4 times the nominal duration (see Figure 6 and Figure 7).

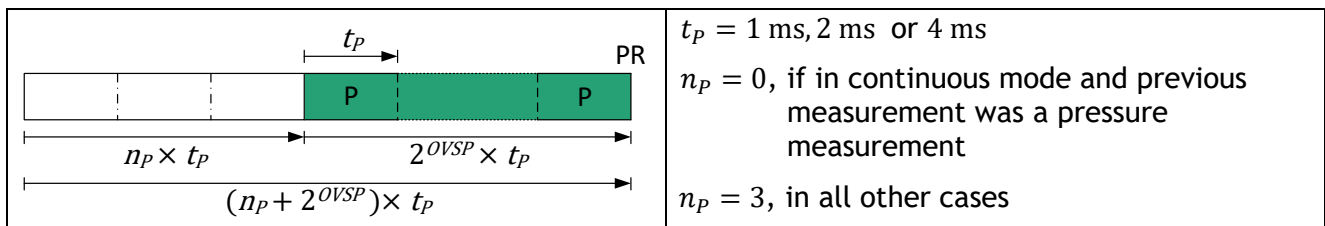


Figure 6: Timing diagram of a pressure pulse (values are typical)

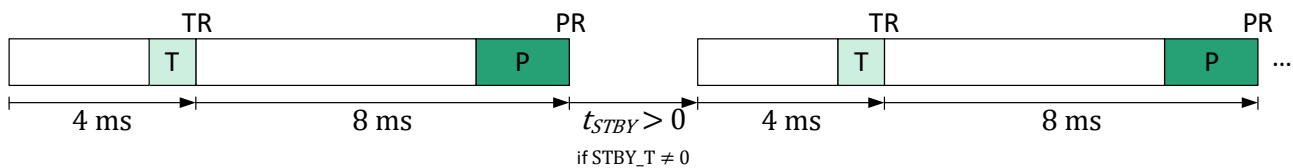


Figure 7: Typical timing for a continuous or pulsed measurement in default configuration. ($PT_RATE = 1$, $P_CONV = 1$ (2 ms) and no oversampling)

Oversampling is available to reduce the measurement noise at the expense of conversion time. Between 1 and 128 measurements (see also [OVS_CFG](#)) are performed and averaged to calculate the output value. Every additional conversion for oversampling takes 1 ms, 2 ms or 4 ms, depending on the conversion time selected (Figure 8). The effect of oversampling on noise is shown in Figure 9.

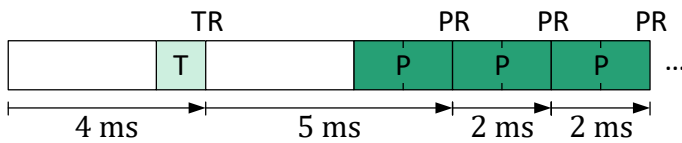


Figure 8: Typical timings for a continuous pressure-only measurement ($P_MEAS = 0$, $P_CONV = 0$) with activated 2× oversampling ($OVSP = 1$)

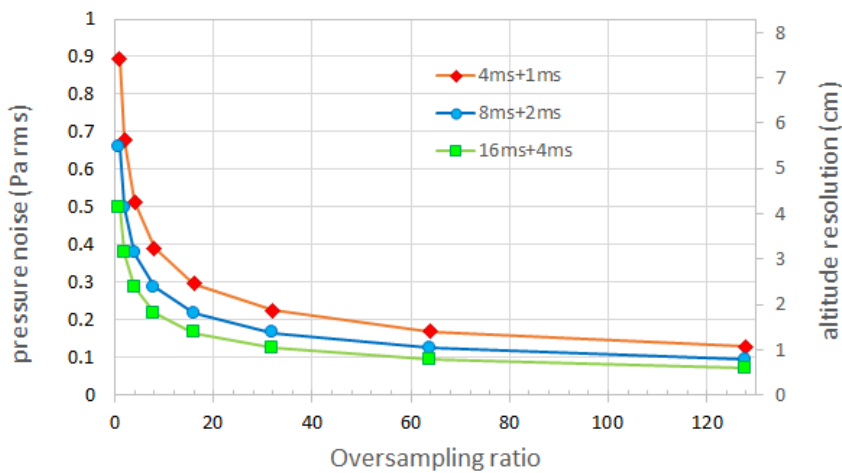


Figure 9: Pressure noise as function of oversampling ratio for three conversion time settings.

The oversampled pressure value can either be transferred directly to the readout registers, can be recorded in a FIFO buffer, or can be further processed by a moving average filter. The desired path is selected by writing on [MODE_CFG.FIFO_MODE](#) (see chapter 6.6 and 6.8).

6.5.2 Temperature

The precision of the temperature output can be optimized by oversampling rate. Between 1 and 128 measurements (see also [OVS_CFG](#)) are performed and averaged to calculate the output value. The temperature conversion time is 4 ms. In case of oversampling, every additional conversion requires 1 ms (see Figure 10).

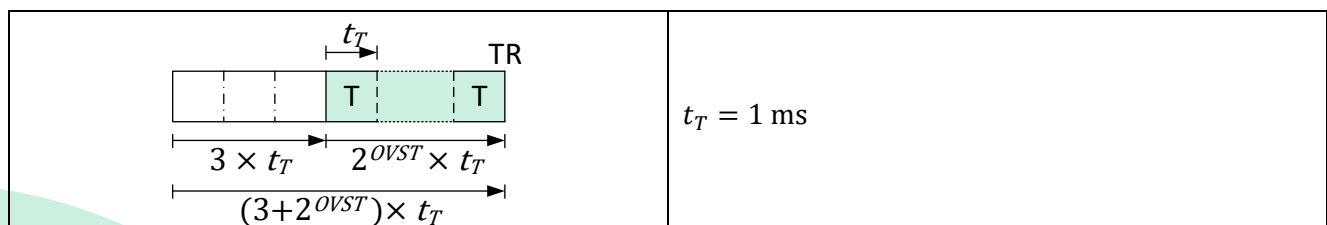


Figure 10: Timing diagram of a temperature pulse (values are typical)

Note: When measuring only temperature, each oversampled measurement will start with a 4 ms time followed by 1 ms for the measurements required to complete oversampling (Figure 11).

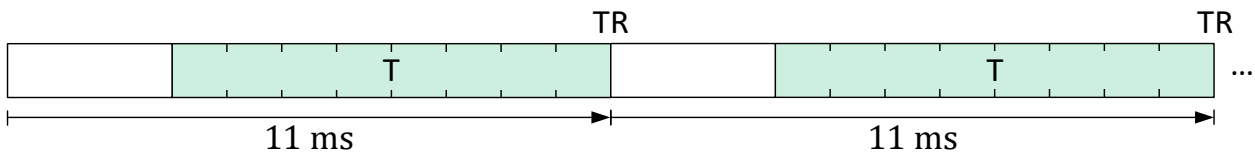


Figure 11: Typical timing of a continuous temperature-only measurement (MEAS_P=0) with 8× oversampling (OVST=3)

6.6 FIFO

A FIFO buffer with 32 positions is available to store pressure values; it is enabled by writing on MODE_CFG.FIFO_MODE.

The FIFO works as a circular buffer, with a write pointer used to store new pressure values and a read pointer used to retrieve them (the structure is shown in Figure 12). The write pointer is increased whenever a new measurement is complete, then the new value is written on the buffer. The pointer will increase even when the buffer is full, overwriting the oldest values recorded. Reads from PRESS_OUT_H increase the read pointer until it reaches the write pointer, subsequent reads will return 0. Both pointers wrap around (31 increments to 0).

Reading the entire FIFO quickly can be done by using PRESS_OUT_F. In this case a continuous read past address 0x29 will cycle the memory read pointer back to 0x27, increasing at the same time the FIFO read pointer. In this way the entire FIFO buffer can be transferred without addressing overhead.

NOTE: in order to read more than one value it is necessary to set the HP bit in MODE_CFG.

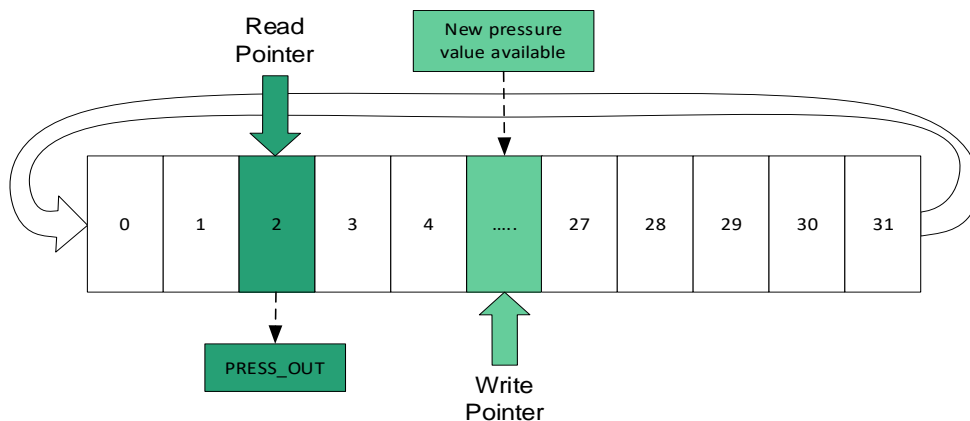


Figure 12: FIFO structure

FIFO operations are controlled by FIFO_CFG. The FIFO can be cleared by setting FP_CLEAR. FIFO status is available in FIFO_STAT and the current FIFO fill level (number of elements available) can be read on FP_FILL. When FIFO is empty, FE is set, when FIFO is full, FF is set. If a new pressure value arrives while FIFO is full, the overrun bit DATA_STAT.PO is set, and the oldest value is overwritten.

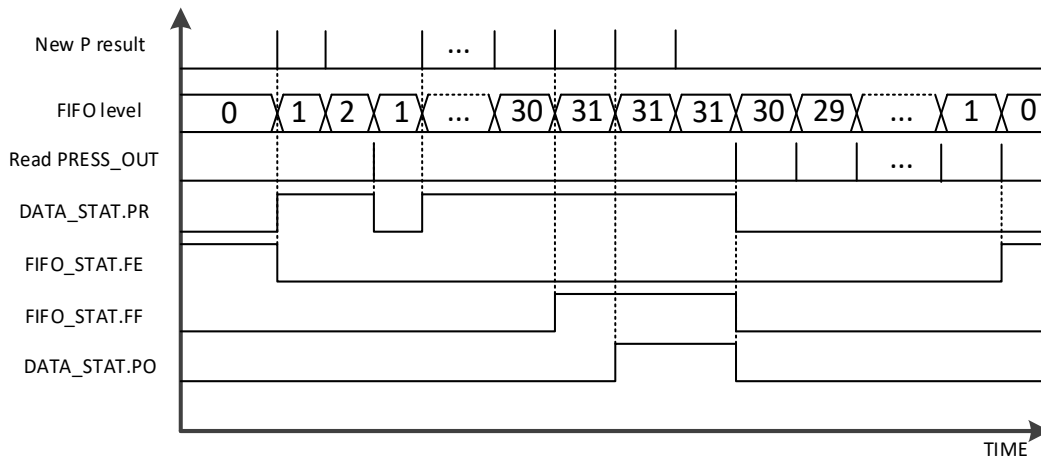


Figure 13: Sample FIFO timing diagram

Interrupts can be configured so that they will assert when FIFO is full, empty or filled to a certain level (see chapter 6.7 and 0)

6.7 Interrupt

Interrupts can be enabled by writing on [INT_CFG](#). Interrupts are available for the following events:

- Pressure measurement ready
- Temperature measurement ready
- FIFO level high
- FIFO full
- FIFO empty
- Pressure below [PRESS_LO](#)
- Pressure above [PRESS_HI](#)

Once an interrupt is asserted, the interrupt source can be read in [INT_STAT](#).

Reading [INT_STAT](#) will automatically clear all interrupt source flags, will clear [IA](#), and will reset the INT/SDOUT pin value to the de-asserted state.

The polarity of the INT pin can be selected by writing on [INTF_CFG](#).

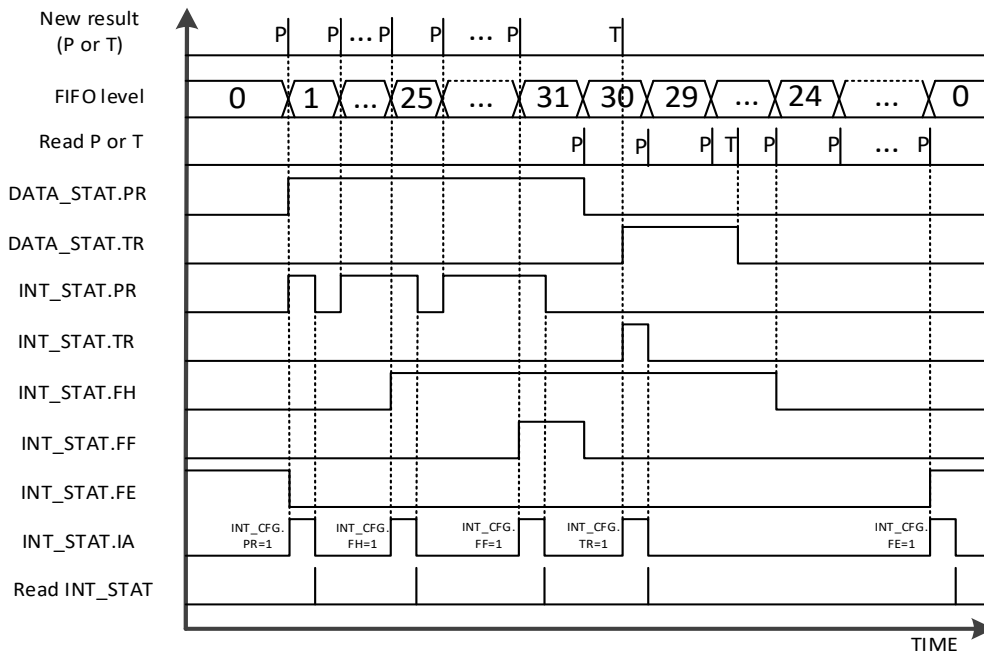


Figure 14: Sample interrupt timing diagram

6.8 Moving average

A moving average filter can be applied to pressure measurements. The filter is enabled by writing on [MODE_CFG.FIFO_MODE](#). The FIFO buffer is used to implement this function, so FIFO is not functional when moving average is enabled.

The window size, i.e. the number of samples used by the moving average filter, is controlled by [MAVG](#) (1 to 32); it should only be changed while the moving average filter is disabled. After moving average is enabled (by setting [MODE_CFG.FIFO_MODE=2](#)), the first pressure value available is used to initialize the window with that first pressure value.

NOTE: moving average settings are independent from pressure oversampling enabled via [OVSP](#). The result of pressure oversampling is processed by the moving average filter (see Figure 15: Moving average example (16 values)).

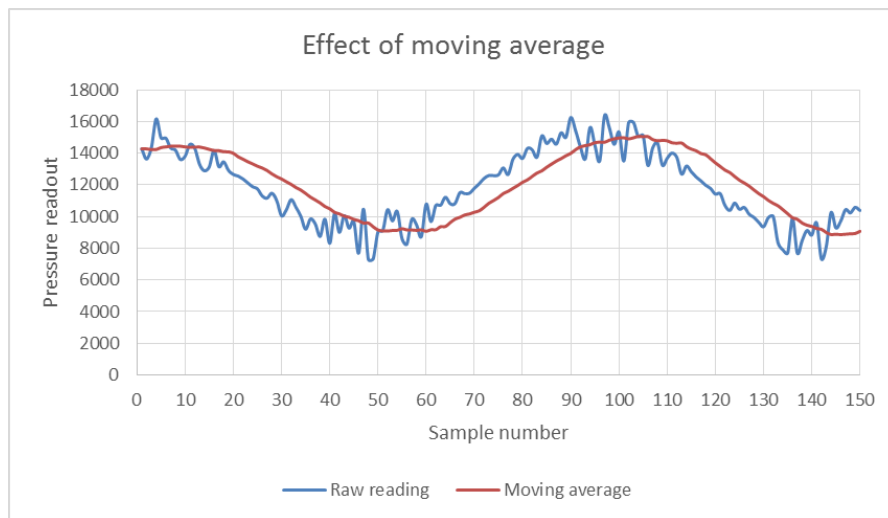


Figure 15: Moving average example (16 values)

7 Digital interface description

The ENS220 can be accessed as a slave device through either SPI 3-wire, SPI 4-wire, or I²C serial interface.

7.1 Interface selection

Selection between I²C and SPI is done through CSN.

If CSN is high, the I²C interface will be active and the SPI interface inactive. For systems where the host communicates via I²C to this device, connect CSN to VDD permanently.

A falling edge of CSN will disable the I²C interface until the next power-on cycle or software reset. The SPI host should make sure to generate a low pulse on CSN before communicating to other devices on the bus, in order to avoid that the device interprets SPI bus traffic as I²C.

7.2 I²C interface

The ENS220 is an I²C slave device with a fixed 7-bit address 0x20.

The I²C interface supports fast (400 kbit/s) and high-speed (3400 kbit/s) mode. Details on I²C protocol is according to I²C-bus specifications [UM10204, I²C-bus specification and user manual, Rev. 6, 4 April 2014].

The device applies all mandatory I²C protocol features for slaves: START, STOP, Acknowledge, 7-bit slave address and also the optional clock stretching. The latter means that the master must support clock stretching in order to successfully communicate with the ENS220. None of the other optional features (10-bit slave address, general call, software reset or Device ID) are supported, nor are the master features (Synchronization, Arbitration, START byte).

The ENS220 uses a register model to interact with the host. This means that the I²C master can directly read or write values to one of the registers by first sending the single byte register address. The ENS220 implements “auto increment” which means that it is possible to read or write multiple bytes (e.g. read multiple DATA_X bytes) in a single transaction.

7.2.1 I²C write operation

After the START (S) condition (which blocks the bus), in a single continuous transaction:

- The I²C Master sends the 7-bit slave address and 0 into the R bit (indicates a write transaction, the byte sent would be 0x40). The transaction will be acknowledged by the slave (ACK).
- The I²C Master then sends the address of the first register to write. The transaction will be acknowledged by the slave (ACK). (or not acknowledged (NACK) when the address is not writable)
- The I²C Master then sends 1-n data bytes which are written into sequential registers (if valid) until the transaction is concluded with a STOP (P) condition.

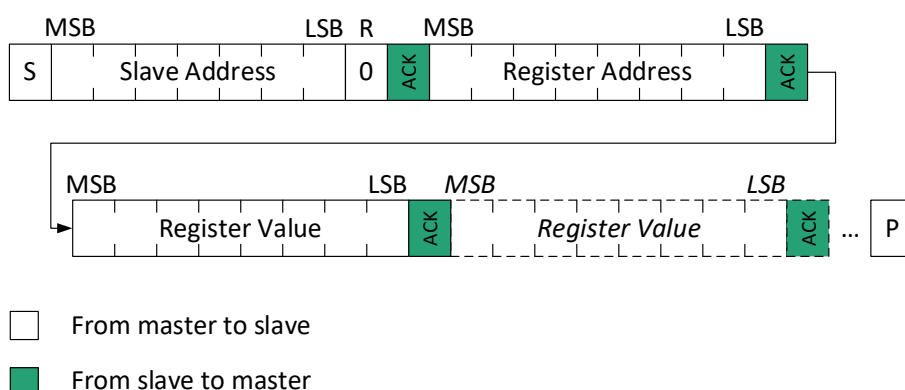


Figure 16: I²C Write operation

7.2.2 I²C read operation

A *read* transaction (see Figure 17) starts with a write (of the register address), followed by a read. Consequently, it has the following format:

After the START condition, in the first transaction:

- The I²C Master sends the 7-bit slave address and 0 into the R bit (indicates a write transaction, the byte sent would be 0x40). The transaction will be acknowledged by the slave (ACK).
- The I²C Master then sends the address of the first register to read.

Then after a repeated START condition by the master:

- The I²C Master sends the 7-bit slave address and 1 into the R bit (indicates a read transaction, the byte sent would be 0x41).
- The I²C slave then sends 1-n data bytes from sequential registers (if valid), each acknowledged by the master until the transaction is concluded with a STOP condition.

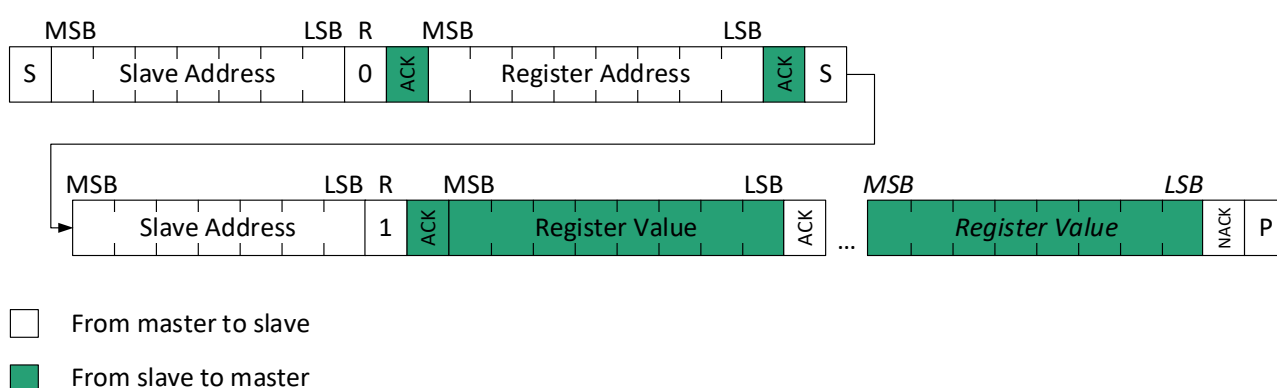


Figure 17: I²C read operation

7.2.3 High speed mode

The bus operation speed is limited to 400 kHz unless a high speed enable command (00001xxx) is issued by the master device as the first byte after START condition. This switches the bus to a high-speed operation which allows data transfer frequencies up to 3.4 MHz. Such command is not acknowledged (NACK) by the slave but the input filter time constant on the serial interface (SDA and

SCL) is adapted to allow higher transfer rate. After a high-speed command, the slave address is transmitted by the master in order to invoke a data transfer. The bus keeps operating at the highest operating frequency until the master issues a STOP condition. Upon reception of the STOP condition by the slave, the input filters are switched to their initial time constants, which allow only up to 400 kHz transfer rates.

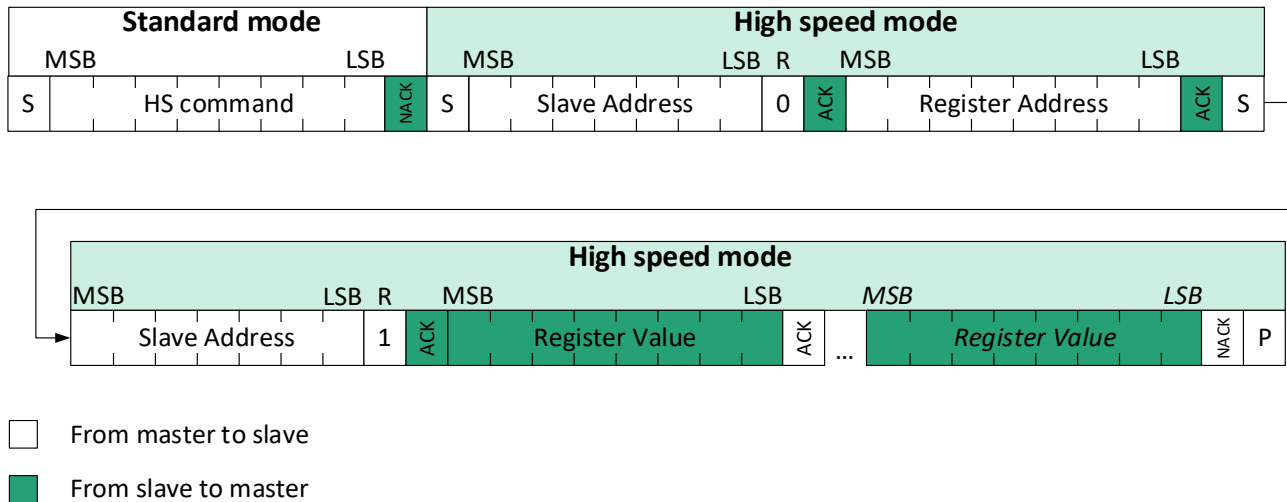


Figure 18: I²C high-speed read operation

7.2.4 Timing specifications

ENS220 is compliant to the I²C bus specifications [UM10204, I²C-bus specification and user manual, Rev. 6, 4 April 2014].

Table 7: ENS220 I²C timing parameters³

| Parameter | Symbol | Units | Fast Mode | | High-Speed Mode | |
|----------------------------------|--------|-------|-----------|-----|-----------------|------|
| | | | Min | Max | Min | Max |
| SCL frequency | Fscl | kHz | | 400 | | 3400 |
| SCL low time | TwscLl | µs | 1.3 | | 0.16 | |
| SCL high time | TwscLh | | 0.6 | | 0.06 | |
| SDA setup time | Tsup | ns | 100 | | 10 | |
| SDA hold time (host transmits) | Th | ns | 0 | - | 0 | - |
| SDA hold time (device transmits) | Tv | ns | 40 | 900 | 20 | 160 |
| SCL rise time | TrCL | ns | | 300 | 10 | 40 |
| SCL fall time | TfCL | | | 300 | 10 | 40 |
| SDA rise time | TrDA | | | 300 | 10 | 80 |

³ All values referred to V_{IHmin} and V_{ILmax} levels.

| | | | | | | |
|-------------------------------------|--------|----|-----|-----|------|-----|
| SDA fall time | TfDA | | | 300 | 10 | 80 |
| Start condition hold time | Thst | μs | 0.6 | | 0.16 | |
| Repeated start condition setup time | Tsupst | | 0.6 | | 0.16 | |
| Stop condition setup time | Tsupsp | | 0.6 | | 0.16 | |
| Bus free time between start-stop | Twspst | | 1.3 | | 0.16 | |
| Load capacitance | CL | pF | | 400 | | 100 |

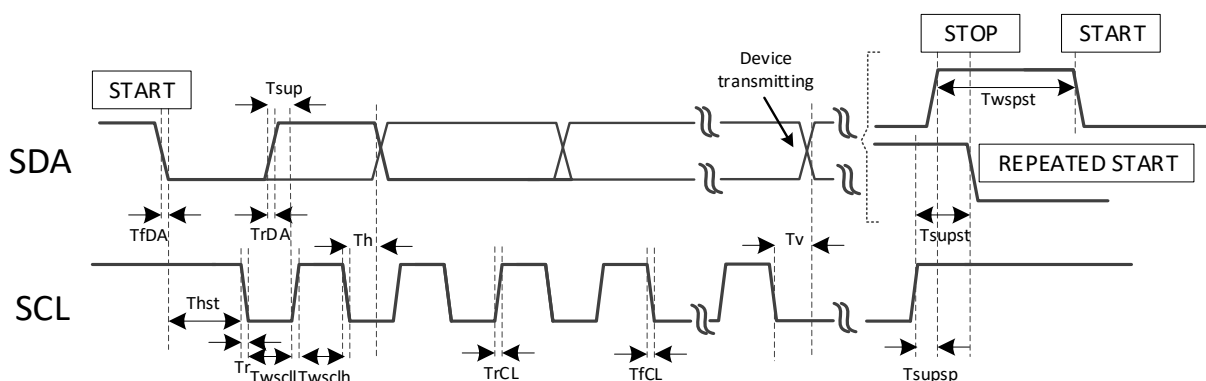


Figure 19: I²C timing diagram

7.3 SPI interface

The ENS220 is an SPI bus slave. The SPI allows to write and read the registers of the device. The serial interface interacts with the outside world with 4 wires: CSN, SCLK, SDIN and SDOUT; an optional 3 wire mode uses a single bi-directional data line instead of two.

CSN is the serial port enable and it is controlled by the SPI master. It is driven low at the start of the SPI frame and returns high at the end.

SCLK is the serial port clock and is controlled by the SPI master. It should stay high in the absence of transmissions. SDIN and SDOUT are respectively the serial port data input and output. Those lines are driven at the falling edge of SCLK and should be captured at the rising edge of SCLK.

The SDOUT pin is shared between SPI output data and interrupt function. When CSN=1 and interrupt functionality is enabled, SDOUT will provide interrupt service.

If interrupts are disabled then SDOUT stays in high impedance mode until data is requested from the device, i.e., during an SPI transaction.

Both the read register and write register commands are completed in 16 clock pulses or in multiples of 8 in the case of multiple bytes read/write. Bit duration is the time between two falling edges of SCLK. The first bit (bit 0) starts at the first falling edge of SCLK after the falling edge of CSN while the last bit (bit 15, bit 23, ...) starts at the last falling edge of SCLK just before the rising edge of CSN.

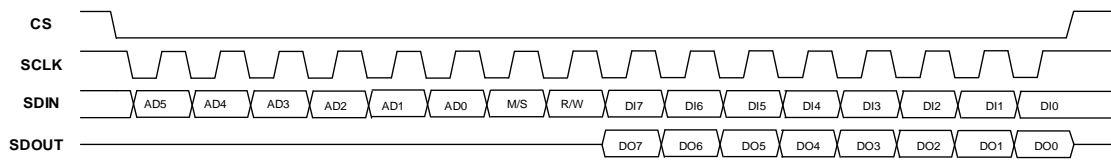


Figure 20: Minimum SPI frame

The device can also work with a low idle value of SCLK (also known as SPI mode 0), as shown below.

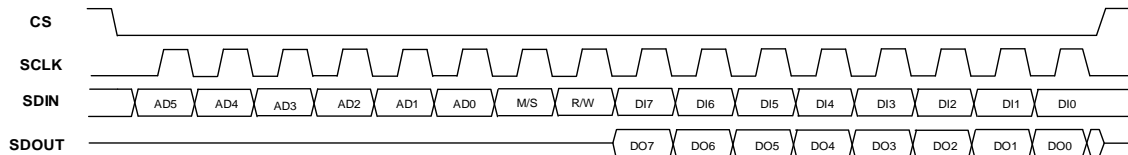


Figure 21: SPI frame using mode 0

A standard SPI frame is organized as follows:

Table 8: SPI frames for reading and writing registers

| Byte | Bit | Name | Description | |
|------|--------------------------------|---------|--|--|
| | | | read | write |
| 0 | 7:2 | AD[5:0] | Address of the indexed register | |
| 0 | 1 | MS | 0: address will be auto incremented in multiple read/write commands. 1: no auto-incrementing of the address | |
| 0 | 0 | RW | 1: data D_i is read from the device. SDOUT becomes active at bit 8. | 0: data D_i is written to the device. |
| 1 | 15:8 | D1[7:0] | Data output from the device (MSB first) to pin SDOUT. | Data written to the device from pin MOSI (MSB first) |
| ... | | | | |
| n | $(8 \times n + 7): 8 \times n$ | D_n | n -th byte output to pin SDOUT (MSB first) | n -th byte input from pin MOSI (MSB first) |

In multiple read/write commands, further blocks of 8 clock periods are added. When the MS bit is 0 the address used to read/write data remains the same for every block. When MS bit is 1 the address used to read/write data is increased at every block. The function and the behavior of SDIN and SDOUT remain unchanged.

7.3.1 SPI write operation

The SPI single byte write command consists of 16 clock pulses. A multiple byte write is performed by adding blocks of 8 clock pulses to the single byte write.

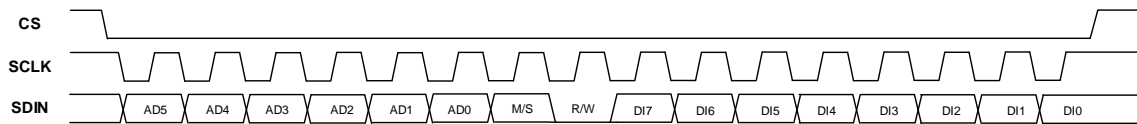


Figure 22: Single byte write

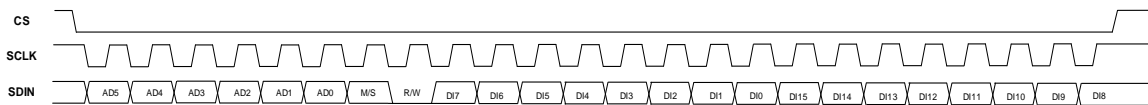


Figure 23: Multiple bytes write (2 bytes)

7.3.2 SPI read operation

The SPI single byte read command consists of 16 clock pulses. A multiple byte read is performed by adding blocks of 8 clock pulses to the single byte read. All register data is copied into an intermediate buffer at the beginning of a read transaction; multiple reads in the same read transaction will refer to the intermediate buffer.

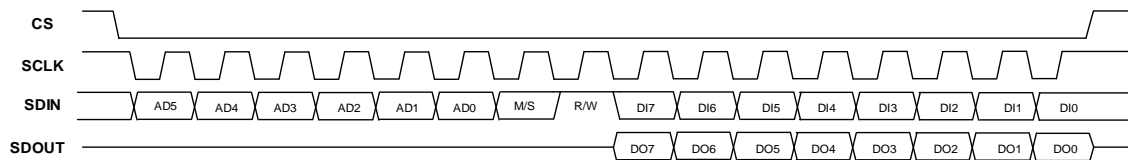


Figure 24: SPI read timing diagram

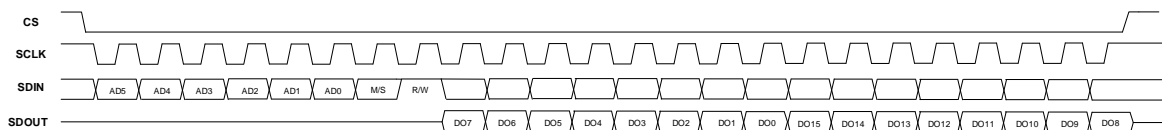


Figure 25: Multiple byte SPI read (2 bytes)

A 3-wire SPI mode can be selected by setting bit SPI3 in the INTF_CFG register. In this case, SDA acts as a bi-directional data line, and should be connected to an external pull-up resistor. Multiple byte read is also available in 3-wire mode.

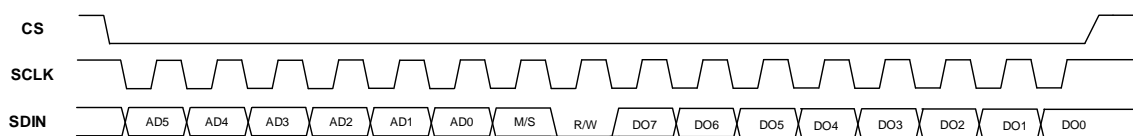


Figure 26: SPI read in 3-wire mode

7.3.3 Timing specifications

| Description | Parameter | Min | Max | Units |
|--|-----------|----------------------|------|-------|
| SPI clock frequency | Fsclk | | 10 | MHz |
| 1/(SPI clock frequency) | Tsclk | 100 | | ns |
| CSN falling edge to SCLK falling edge | Tdel | 25 | | ns |
| SCLK rising edge to CSN rising edge | Tquiet | 25 | | ns |
| CSN rising edge to SDO disabled | Tdis | | 50 | ns |
| CSN deassertion between SPI communications | Tcs_dis | 100 | | ns |
| SCLK low pulse width | Ts | $0.4 \cdot t_{SCLK}$ | | ns |
| SCLK high pulse width | Tm | $0.4 \cdot t_{SCLK}$ | | ns |
| SDI valid before SCLK rising edge | Tsetup | 25 | | ns |
| SDI valid after SCLK rising edge | Thold | 25 | | ns |
| SCLK falling edge to SDO output transition | Tsdo | | 40 | ns |
| SDO output low to output high transition | Tr | | 11.5 | ns |
| SDO output high to output low transition | Tf | | 11.5 | ns |
| Capacitance load at SDO pin | CL | | 25 | pF |

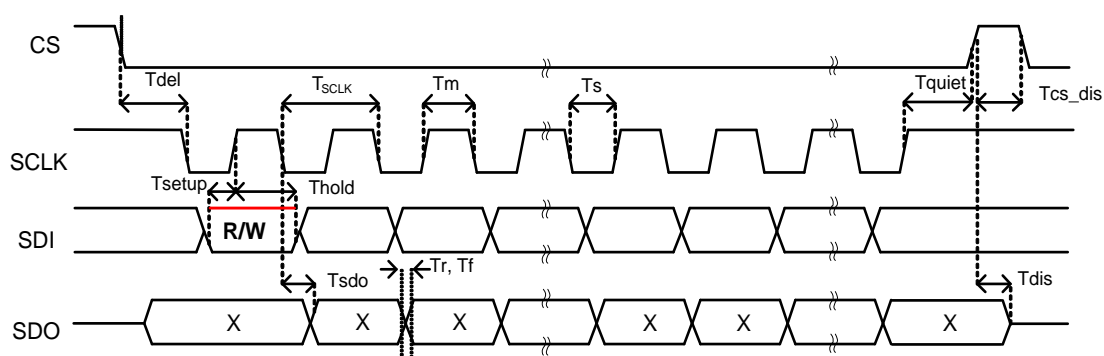


Figure 27: SPI timing diagram

8 Registers

This section describes the registers of the ENS220.

8.1 Register map

Table 9: Register map

| Adr. | Name | Default | R/W | 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 | Description |
|------|--------------------------------|---------|------|----------------|-----------|--------|------------|---------|--------|--------|----|------------------------------|
| 0x00 | PART_ID0 | 0x2X | Rr | PART_ID0 | | | | | | | | Part ID [7:0] |
| 0x01 | PART_ID1 | 0x03 | Rr | PART_ID1 | | | | | | | | Part ID [15:8] |
| 0x02 | UID0 | | R | UID0 | | | | | | | | Unit ID [7:0] |
| 0x03 | UID1 | | R | UID1 | | | | | | | | Unit ID [15:8] |
| 0x04 | UID2 | | R | UID2 | | | | | | | | Unit ID [23:16] |
| 0x05 | UID3 | | R | UID3 | | | | | | | | Unit ID [31:24] |
| 0x06 | MODE_CFG | 0x00 | RWrw | HP | FIFO_MODE | START | RESET | 0 | MEAS_T | MEAS_P | | Device configuration |
| 0x07 | MEAS_CFG | 0x08 | RW | 0 | 0 | P_CONV | | PT_RATE | | | | Conversion time, P/T rate |
| 0x08 | STBY_CFG | 0x00 | RWw | 0 | | | | STBY_T | | | | Standby time configuration |
| 0x09 | OVS_CFG | 0x00 | RW | 0 | | OVSP | | | OVST | | | Oversampling settings |
| 0x0A | MAVG_CFG | 0x00 | RW | 0 | | | | MAVG | | | | Moving average config. |
| 0x0B | INTF_CFG | 0x00 | RWw | 0 | | | | INT_EN | INT_HL | SPI3 | | Interface configuration |
| 0x0C | INT_CFG | 0x7F | RWw | 0 | TR | FH | FF | FE | PR | PH | PL | Interrupt mask configuration |
| 0x0D | PRESS_LO_XL | 0x00 | RW | PRESS_LO_XL | | | | | | | | Low press. threshold [7:0] |
| 0x0E | PRESS_LO_L | 0x00 | RW | PRESS_LO_L | | | | | | | | Low press. threshold [15:8] |
| 0x0F | PRESS_LO_H | 0x00 | RW | PRESS_LO_H | | | | | | | | Low press. threshold [23:16] |
| 0x10 | PRESS_HI_XL | 0xFF | RW | PRESS_HI_XL | | | | | | | | High press. threshold [7:0] |
| 0x11 | PRESS_HI_L | 0xFF | RW | PRESS_HI_L | | | | | | | | High press. threshold [15:8] |
| 0x12 | PRESS_HI_H | 0xFF | RW | PRESS_HI_H | | | | | | | | High P threshold [23:16] |
| 0x13 | FIFO_CFG | 0x00 | RW | 0 | FP_CLEAR | | FP_FILL_TH | | | | | FIFO configuration |
| 0x14 | DATA_STAT | 0x00 | Rr | 0 | | | | PO | TO | PR | TR | Measurement data status |
| 0x15 | FIFO_STAT | 0x02 | R | FP_FILL | | | | | FF | FE | FH | FIFO status |
| 0x16 | INT_STAT | 0x08 | Rr | IA | TR | FH | FF | FE | PR | PH | PL | Interrupt status |
| 0x17 | PRESS_OUT_XL | 0x00 | Rry | PRESS_OUT_XL | | | | | | | | Pressure value [7:0] |
| 0x18 | PRESS_OUT_L | 0x00 | Rry | PRESS_OUT_L | | | | | | | | Pressure value [15:8] |
| 0x19 | PRESS_OUT_H | 0x00 | Rry | PRESS_OUT_H | | | | | | | | Pressure value [23:16] |
| 0x1A | TEMP_OUT_L | 0x00 | Rr | TEMP_OUT_L | | | | | | | | Temperature value [7:0] |
| 0x1B | TEMP_OUT_H | 0x00 | Rr | TEMP_OUT_H | | | | | | | | Temperature value [15:8] |
| 0x27 | PRESS_OUT_F_XL | 0x00 | RFry | PRESS_OUT_F_XL | | | | | | | | Pressure value [7:0] |
| 0x28 | PRESS_OUT_F_L | 0x00 | RFry | PRESS_OUT_F_L | | | | | | | | Pressure value [15:8] |
| 0x29 | PRESS_OUT_F_H | 0x00 | RFry | PRESS_OUT_F_H | | | | | | | | FIFO Pressure value [23:16] |

Legend: (the letters in the R/W column define the colours of the register fields)

W Write access in low power mode
R Read access in low power mode
F Address counter wraps. See text.

w Write access in ultra-low power mode
r Read access in ultra-low power mode
y Read only the last value in ultra-low power mode

0 Must write 0
0 Reads 0

Note that some registers are spread over multiple addresses. For example, PART_ID at address 0 is spread over 2 addresses (its “Size” is 2). Registers are stored in little endian so the LSB of PART_ID is at address 0 and the MSB of PART_ID is at address 1.

8.2 Detailed register description

8.2.1 PART_ID (Address 0x00-0x01)

The value is available when the ENS220 is initialized after power-up.

Table 10: Register PART_ID

| PART_ID | | | | | |
|---------|------|------------|---------|--------|---|
| Address | Bits | Field Name | Default | Access | Field Description |
| 0x00 | 7:0 | PART_ID0 | 0x2X | Rr | Least significant byte (LSB) of Part ID |
| 0x01 | 15:8 | PART_ID1 | 0x03 | Rr | Most significant byte (MSB) of Part ID |

8.2.2 UID (Address 0x02-0x05)

32 bit unique device identifier

Table 11: Register UID

| UID | | | | | |
|---------|-------|------------|---------|--------|-------------------------------------|
| Address | Bits | Field Name | Default | Access | Field Description |
| 0x02 | 7:0 | UID0 | | R | Least significant byte (LSB) of UID |
| 0x03 | 15:8 | UID1 | | R | Second byte of UID |
| 0x04 | 23:16 | UID2 | | R | Third byte of UID |
| 0x05 | 31:24 | UID3 | | R | Most significant byte (MSB) of UID |

8.2.3 MODE_CFG (Address 0x06)

Table 12: Register MODE_CFG

| Address 0x06 | | MODE_CFG | | Default: 0x00 |
|--------------|------------|----------|--------|---|
| Bits | Field Name | Default | Access | Field Description |
| 7 | HP | 0b0 | RWrw | <p>High Power Bit</p> <p>0b1: All registers are accessible via SPI/I²C; power consumption is high. A delay of 0.5 ms is required from high power enable to the next SPI/I²C access.</p> <p>0b0: The following registers are accessible via SPI/I²C: MODE_CFG, PART_ID[1:0], DATA_STAT, FIFO_STAT, PRESS_OUT, TEMP_OUT, INT_STAT. Power consumption is low.</p> |
| 6:5 | FIFO_MODE | 0b00 | RWrw | <p>Pressure data path</p> <p>0b00: Direct path</p> <p>0b01: FIFO</p> <p>0b10: Moving average</p> |
| 4 | START | 0b0 | RWrw | <p>Operating mode configuration</p> <p>0b0: Stop measurements (idle mode)</p> <p>0b1: Start measurements (measurement mode)</p> <p>Idle Mode is intended for configuration before running an active sensing mode.</p> <p>This bit is automatically reset in case of one-shot operation, after the required measurements have been performed</p> |
| 3 | RESET | 0b0 | RWrw | <p>Device reset</p> <p>0b1: The device is reset to the power-on configuration. RESET is automatically cleared</p> <p>Device reset should be performed with HP bit at 0; the suggested reset sequence is:</p> <p>0x08 → wait 0.5 ms → 0x80 → wait 0.5 ms → configure device</p> |
| 2 | X | 0b0 | RWrw | Reserved – must be set to default value |
| 1 | MEAS_T | 0b0 | RWrw | See Table 13 |
| 0 | MEAS_P | 0b0 | RWrw | |

Table 13: MEAS_T, MEAS_P: measurement selection

| MEAS_T | MEAS_P | |
|--------|--------|---|
| 0 | 1 | Only pressure measurements are enabled; the device will begin with a temperature measurement, then it will continue measuring only pressure |
| 1 | 0 | Only temperature measurement is enabled. |
| 1 | 1 | Pressure and temperature measurements are enabled. PT_RATE controls the temperature interleaving timer |

8.2.4 MEAS_CFG (Address 0x07)

Table 14: Register MEAS_CFG

| Address 0x07 | | MEAS_CFG | | | Default: 0x08 |
|--------------|------------|----------|--------|--|---------------|
| Bits | Field Name | Default | Access | Field Description | |
| 7:5 | X | 0b0 | RW | Reserved – needs to be set to default value | |
| 4:3 | P_CONV | 0b01 | RW | Pressure ADC conversion time (see Table 15) | |
| 2:0 | PT_RATE | 0b000 | RW | Determines the ratio between P and T measurements as produced by the measurement engine (see Table 16) | |

Table 15: Typical pressure ADC conversion time

| P_CONV[1:0] | Conversion time [ms] First conversion | Conversion time [ms] Next conversions |
|-------------|--|--|
| 0 | 4 | 1 |
| 1 | 8 | 2 |
| 2 | 16 | 4 |

Table 16: PT_RATE

| PT_RATE[2:0] | P/T rate |
|--------------|----------|
| 0 | 1 |
| 1 | 4 |
| 2 | 8 |
| 3 | 16 |
| 4 | 32 |
| 5 | 64 |
| 6 | 128 |
| 7 | 256 |

8.2.5 STBY_CFG (Address 0x08)

Table 17: Register STBY_CFG

| Address 0x08 | | STBY_CFG | | | Default: 0x00 |
|--------------|------------|----------|--------|--|---------------|
| Bits | Field Name | Default | Access | Command | |
| 7:4 | X | 0x0 | RWw | Reserved, needs to be set to default value | |
| 3:0 | STBY_T | 0x0 | RWw | Measurements will be alternated with a standby phase. (see Table 18) | |

Table 18: Measurements will be alternated with a standby phase with the following duration:

| STBY_T[3:0] | Standby time (ms) |
|-------------|---|
| 0 | Continuous operation |
| 1 | One-shot operation (device returns to idle after one measurement is produced by the measurement engine) |
| 2 | 10 |
| 3 | 20 |
| 4 | 30 |
| 5 | 50 |
| 6 | 100 |
| 7 | 250 |
| 8 | 500 |
| 9 | 750 |
| 10 | 1000 |
| 11 | 2000 |
| 12 | 5000 |
| 13 | 10000 |
| 14 | 60000 |
| 15 | 600000 |

8.2.6 OVS_CFG (Address 0x09)

Oversampling works by averaging the value of a certain number of samples. Oversampling applies to all measurement modes.

Table 19: Register OVS_CFG

| Address 0x09 | | OVS_CFG | | | Default: 0x00 |
|--------------|------------|---------|--------|---|---------------|
| Bits | Field Name | Default | Access | Field Description | |
| 7:6 | X | 0b00 | RW | Reserved, must be set to default value | |
| 5:3 | OVSP | 0b000 | RW | Oversampling of pressure measurements (see Table 20) | |
| 2:0 | OVST | 0b000 | RW | Oversampling of temperature measurements (see Table 21) | |

Table 20: Oversampling of pressure measurements

| OVSP[5:3] | Number of averages |
|-----------|--------------------|
| 0 | 1 |
| 1 | 2 |
| 2 | 4 |
| 3 | 8 |
| 4 | 16 |
| 5 | 32 |
| 6 | 64 |
| 7 | 128 |

Table 21: Oversampling of temperature measurements

| OVST[2:0] | Number of averages |
|-----------|--------------------|
| 0 | 1 |
| 1 | 2 |
| 2 | 4 |
| 3 | 8 |
| 4 | 16 |
| 5 | 32 |
| 6 | 64 |
| 7 | 128 |

8.2.7 MAVG_CFG (Address 0x0A)

Moving average configuration

Table 22: Register MAVG_CFG

| Address 0x0A | | MAVG_CFG | | | Default: 0x00 |
|--------------|------------|----------|--------|--|---------------|
| Bits | Field Name | Default | Access | Field Description | |
| 7:3 | X | 0x00 | RW | Reserved, must be set to default value | |
| 2:0 | MAVG | 0b00 | RW | Controls the number of samples used by the moving average filter. (see Table 23) | |

Table 23: Moving average configuration

| MAVG[2:0] | Samples |
|-----------|---------|
| 0 | 1 |
| 1 | 2 |
| 2 | 4 |
| 3 | 8 |
| 4 | 16 |
| 5 | 32 |
| 6 | 32 |
| 7 | 32 |

8.2.8 INTF_CFG (Address 0x0B)

Host interface configuration register

Table 24: Register INTF_CFG

| Address 0x0B | | INTF_CFG | | | Default: 0x00 |
|--------------|------------|----------|--------|---|---------------|
| Bits | Field Name | Default | Access | Field Description | |
| 7:3 | X | 0x0 | RWw | Reserved, must be set to default value | |
| 2 | INT_EN | 0b0 | RWw | Interrupt enable 0b1: INT/SDOUT is controlled by INT_STAT.IA 0b0: INT/SDOUT is always low | |
| 1 | INT_HT | 0b0 | RWw | Interrupt polarity 0b1: INT/SDOUT low signals that interrupt is asserted 0b0: high signals that interrupt is asserted | |
| 0 | SPI3 | 0b0 | RWw | SPI mode control 0b1: SPI works in 3-wire mode 0b0: SPI works in 4-wire mode | |

8.2.9 INT_CFG (Address 0x0C)

Interrupt configuration register.

Table 25: Register INT_CFG

| Address 0x0C | | INT_CFG | | | Default: 0x7F |
|--------------|------------|---------|--------|--|---------------|
| Bits | Field Name | Default | Access | Field Description | |
| 7 | X | 0b0 | RWw | Reserved, must be set to default value | |
| 6 | TR | 0b1 | RWw | Temperature data ready 0b1: interrupt is triggered when new temperature data becomes available 0b0: interrupt disabled | |
| 5 | FH | 0b1 | RWw | Pressure FIFO level high 0b1: interrupt is triggered when the filling level of the pressure FIFO becomes greater than the programmed level in FP_FILL_TH 0b0: interrupt disabled | |
| 4 | FF | 0b1 | RWw | Pressure FIFO is full 0b1: interrupt is triggered when the pressure FIFO becomes full (32 values) 0b0: interrupt disabled | |
| 3 | FE | 0b1 | RWw | Pressure FIFO is empty 0b1: interrupt is triggered when the pressure FIFO becomes empty 0b0: interrupt disabled | |
| 2 | PR | 0b1 | RWw | Pressure data is available 0b1: interrupt is triggered when new pressure data becomes available 0b0: interrupt disabled | |
| 1 | PH | 0b1 | RWw | Pressure is high 0b1: interrupt is triggered when the pressure is greater than the programmed pressure high threshold (PRESS_HI). 0b0: interrupt disabled | |
| 0 | PL | 0b1 | RWw | Pressure is low 0b1: interrupt is triggered when the pressure is lower than the programmed pressure low threshold (PRESS_LO). | |

| | | | | |
|--|--|--|--|-------------------------|
| | | | | 0b0: interrupt disabled |
|--|--|--|--|-------------------------|

8.2.10 PRESS_LO (Address 0x0D-0x0F)

This 3-byte register sets the pressure threshold for the low-pressure interrupt.

Table 26: Register PRESS_LO

| PRESS_LO | | | | | |
|----------|-------|-------------|---------|--------|--|
| Address | Bits | Field Name | Default | Access | Field Description |
| 0x0D | 7:0 | PRESS_LO_XL | 0x00 | RW | Least significant byte (LSB) of PRESS_LO |
| 0x0E | 15:8 | PRESS_LO_L | 0x00 | RW | Middle Byte of PRESS_LO |
| 0x0F | 23:16 | PRESS_LO_H | 0x00 | RW | Most significant byte (MSB) of PRESS_LO |

8.2.11 PRESS_HI (Address 0x10-0x12)

This 3-byte register sets the pressure threshold for the high pressure interrupt.

Table 27: Register PRESS_HI

| PRESS_HI | | | | | |
|----------|-------|-------------|---------|--------|--|
| Address | Bits | Field Name | Default | Access | Field Description |
| 0x10 | 7:0 | PRESS_HI_XL | 0x00 | RW | Least significant byte (LSB) of PRESS_HI |
| 0x11 | 15:8 | PRESS_HI_L | 0x00 | RW | Middle Byte of PRESS_HI |
| 0x12 | 23:16 | PRESS_HI_H | 0x00 | RW | Most significant byte (MSB) of PRESS_HI |

8.2.12 FIFO_CFG (Address 0x13)

FIFO configuration register

Table 28: Register FIFO_CFG

| Address 0x13 | | FIFO_CFG | | | Default: 0x00 |
|--------------|------------|----------|--------|---|---------------|
| Bits | Field Name | Default | Access | Field Description | |
| 7:6 | X | 0b00 | RW | Reserved, must be set to default value | |
| 5 | FP_CLEAR | 0x00 | RW | FIFO clear. 0b1: the content of the FIFO is cleared; FP_CLEAR is automatically cleared. 0b0: no operation | |
| 4:0 | FP_FILL_TH | 0x00 | RW | FIFO level threshold. The value is used as target for interrupt and status generation. | |

8.2.13 DATA_STAT (Address 0x14)

Data status register

Table 29: Register DATA_STAT

| Address 0x14 | | DATA_STAT | | | Default: 0x00 |
|--------------|------------|-----------|--------|--|---------------|
| Bits | Field Name | Default | Access | Field Description | |
| 7:4 | X | 0x0 | Rr | Reserved | |
| 3 | PO | 0b0 | Rr | Pressure overwrite With FIFO enabled (MODE_CFG.FIFO_MODE=1), this bit is set whenever a new pressure measurement is produced by the measurement engine while the pressure FIFO was already full. PO is cleared after reading PRESS_OUT_H or PRESS_OUT_F_H. With FIFO disabled PO is undefined. | |
| 2 | TO | 0b0 | Rr | Temperature overwrite This bit is set when a new temperature measurement is produced by the measurement engine and the previous data was not read. TO is cleared after reading TEMP_OUT_H. | |
| 1 | PR | 0b0 | Rr | Pressure ready. | |

| | | | | |
|---|----|-----|----|---|
| | | | | This bit is set when new pressure data becomes available. PR is cleared after reading PRESS_OUT_H. |
| 0 | TR | 0b0 | Rr | Temperature ready This bit is set when new temperature data becomes available. TR is cleared after reading TEMP_OUT_H. |

8.2.14 FIFO_STAT (Address 0x15)

FIFO status register

Table 30: Register FIFO_STAT

| Address 0x15 | | FIFO_STAT | | | Default: 0x02 |
|--------------|------------|-----------|--------|--|---------------|
| Bits | Field Name | Default | Access | Field Description | |
| 7:3 | FP_FILL | 0x0 | R | FIFO level Fill level of the pressure FIFO. FP_FILL is equal to 0x1F when FIFO has 31 but also 32 elements. | |
| 2 | FF | 0b0 | R | FF is set when the FIFO is enabled and is full (32 elements). | |
| 1 | FE | 0b1 | R | FE is set when the FIFO is enabled and is empty (0 elements). | |
| 0 | FH | 0b0 | R | FH is set when is enabled and the number of elements is greater than FP_FILL_TH. | |

8.2.15 INT_STAT (Address 0x16)

Interrupt status register. Each bit except IA is set if the corresponding interrupt source has generated an event (even if the hardware interrupt is disabled by the [INT_CFG](#) register). Reading this register will clear all flags.

Table 31: Register FIFO_STAT

| Address 0x16 | | FIFO_STAT | | | Default: 0x00 |
|--------------|------------|-----------|--------|--|---------------|
| Bits | Field Name | Default | Access | Field Description | |
| 7 | IA | 0b0 | Rr | General interrupt flag It is set if any of the interrupt flags (bits 6:0) relative to sources enabled in INT_CFG are set; see also INTF_CFG.INT_EN. | |
| 6 | TR | 0b0 | Rr | TR is set when a new temperature measurement is produced by the measurement engine | |
| 5 | FH | 0b0 | Rr | FH is set when FP_FILL > FP_FILL_TH. | |
| 4 | FF | 0b0 | Rr | FF is set when the FIFO becomes full. | |
| 3 | FE | 0b0 | Rr | FE is set when FIFO becomes empty as effect of a data read. | |
| 2 | PR | 0b0 | Rr | PR is set when new pressure measurement is produced (i.e. without considering oversampling; refer to Figure 22). | |
| 1 | PH | 0b0 | Rr | PH is set when the measurement engine produces a pressure measurement that is greater than PRESS_HI. | |
| 0 | PL | 0b0 | Rr | PL is set when the measurement engine produces a pressure measurement that is lower than PRESS_LO. | |

8.2.16 PRESS_OUT (Address 0x17-0x19)

This 3-byte register contains a 24-bit unsigned integer representing the pressure in 1/64 Pa.

When the FIFO is enabled, a read on this register extracts one element from the FIFO. When the FIFO is empty, the read returns 0x000000.

When the FIFO is not enabled (bypass or moving average), reads from this register return the latest measurement result. If reads occur faster than measurements, values are repeated.

To ensure a consistent value during readout, [PRESS_OUT](#) registers are double buffered. When [PRESS_OUT_XL](#) is read, the device copies all bytes from the internal measurement registers to the I²C registers, then reads are always directly from the I²C/SPI registers. The double buffering is thus only available if all [PRESS_OUT](#) registers are read within the same I²C or SPI transaction (see sections

7.2.2, 7.3.2). If the application does not support reading multiple bytes at once, then the user must ensure that the [PRESS_OUT](#) register is not updated during the reading. This can be achieved by reading quickly after an interrupt occurred, or by using the single-shot mode ([STBY_CFG](#) = 1)

Please note that the hardware implementation of this double buffering does not guarantee the alignment between data ready flags and data if they are accessed in the same I²C/SPI transaction. It is advised to access the flags in a separate transaction.

NOTE: [HP](#) must be 1 when reading this register with [FIFO_MODE](#)=1 to access the whole FIFO.

Table 32: Register [PRESS_OUT](#)

| PRESS_OUT | | | | | |
|---------------------------|-------|------------------------------|---------|--------|---|
| Address | Bits | Field Name | Default | Access | Field Description |
| 0x17 | 7:0 | PRESS_OUT_XL | 0x00 | Rry | Least significant byte (LSB) of PRESS_OUT |
| 0x18 | 15:8 | PRESS_OUT_L | 0x00 | Rry | Middle byte of PRESS_OUT |
| 0x19 | 23:16 | PRESS_OUT_H | 0x00 | Rry | Most significant byte (MSB) of PRESS_OUT |

Example: For a stored [PRESS_OUT](#) value of 0x62F340 the absolute pressure in Pa is calculated as follows:

$$P = \frac{0x062F340}{64} \text{ Pa} = 101325 \text{ Pa}$$

See section 6.3.1 for further information.

8.2.17 [TEMP_OUT](#) (Address 0x1A-0x1B)

This 2-byte register contains a 16-bit unsigned integer representing the temperature in 1/128 K.

Reads from this register return the latest measurement result. If reads occur faster than measurements, values are repeated.

To ensure a consistent value during readout, [TEMP_OUT](#) registers are double buffered. When [TEMP_OUT_L](#) is read, the device copies all bytes from the internal measurement registers to the I²C/SPI registers, then reads are always directly from the I²C/SPI registers. The hardware implementation does to guarantee the alignment between data ready flags and data if they are accessed in the same I²C or SPI transition; it is advised to access the flags separately from the data. But please note that double buffering only works for [TEMP_OUT](#) if [TEMP_OUT_L](#) and [TEMP_OUT_H](#) are read in the same I²C or SPI transaction with auto-increment of the register address (see 7.2.2).

Table 33: Register *TEMP_OUT*

| TEMP_OUT | | | | | |
|----------|------|------------|---------|--------|--|
| Address | Bits | Field Name | Default | Access | Field Description |
| 0x1A | 7:0 | TEMP_OUT_L | 0x00 | Rr | Least significant byte (LSB) of TEMP_OUT |
| 0x1B | 15:8 | TEMP_OUT_H | 0x00 | Rr | Most significant byte (MSB) of TEMP_OUT |

Example: For a stored [TEMP_OUT](#) value of 0x9513, the temperature in degrees Celsius is calculated as follows:

$$T_c = \frac{0x9513}{128} K - 273.15 K \approx 25 ^\circ C$$

See section 6.3.2 for further information.

8.2.18 PRESS_OUT_F (Address 0x27-0x29)

This register is the same as PRESS_OUT, except that reading in a single I²C/SPI transaction wraps around from address 0x29 to 0x27. A single I²C/SPI transaction can thus read multiple P measurements from the FIFO.

NOTE: [HP](#) must be 1 when reading this register to access the whole FIFO.

Table 34: Register *PRESS_OUT_F*

| PRESS_OUT_F | | | | | |
|-------------|-------|----------------|---------|--------|---|
| Address | Bits | Field Name | Default | Access | Field Description |
| 0x27 | 7:0 | PRESS_OUT_F_XL | 0x00 | RFry | Least significant byte (LSB) of PRESS_OUT_F |
| 0x28 | 15:8 | PRESS_OUT_F_L | 0x00 | RFry | Middle byte of PRESS_OUT_F |
| 0x29 | 23:16 | PRESS_OUT_F_H | 0x00 | RFry | Most significant byte (MSB) of PRESS_OUT_F |

9 Application information and use case examples

9.1 I²C operation circuitry

The recommended application circuit for the ENS220 I²C interface operation is shown in Figure 28.

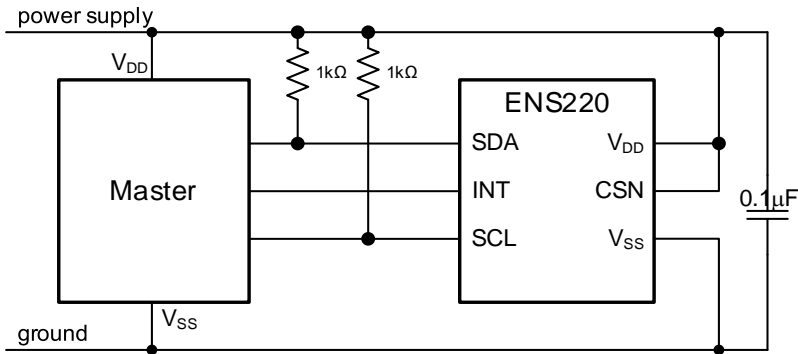


Figure 28: Recommended application circuit (I²C operation)

Note(s):

1. CSn must be pulled high (directly to V_{DD}) to ensure I²C interface is selected.
2. Pull-up resistors.
The above recommendation for pull-up resistance values applies to I²C standard mode only. Pull-up resistors for SCL and SDA are assumed to be part of the host system and should be selected dependent on the intended I²C data rate and individual bus architecture.
3. Decoupling capacitor must be placed close to the V_{DD} supply pin (pin 10) of the ENS220.

9.2 SPI operation circuitry

9.2.1 Three wire SPI

The recommended application circuit for the ENS220 for three wire SPI interface is shown in Figure 29.

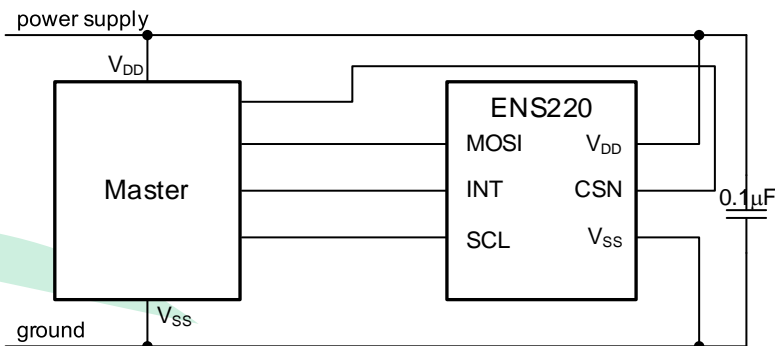


Figure 29: Recommended application circuit (three wire SPI operation)

9.2.2 Four wire SPI

The recommended application circuit for the ENS220 for four wire SPI interface is shown in Figure 30.

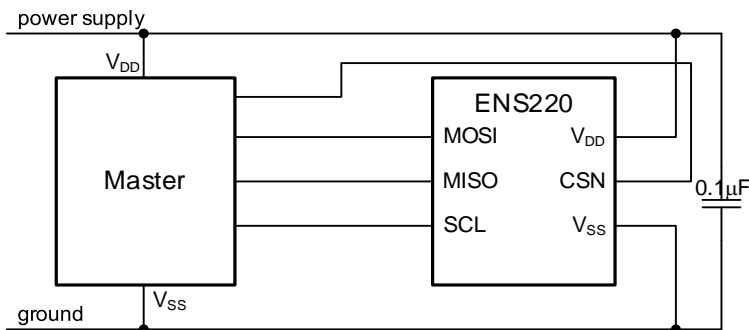


Figure 30: Recommended application circuit (four wire SPI operation)

9.3 Recommended settings for different use cases

Table 35 lists relevant use cases with the associated configuration parameters and the expected performance with these settings.

NOTE: current consumption due to the communication interface used (I²C or SPI) is not included.

Table 35: Relevant use-cases with the associated configuration parameters and typical performance

| Application examples | HP | P CONV | PT RATE | STBY T | OVSP | OVST | Performance |
|---|----|--------|---------|-------------------|------|------|----------------------------------|
| Highest data rate - door/window opening detection | 1 | 1 ms | 128 | 0 ms (continuous) | 1x | 1x | 1.8 Pa noise 1000 Hz 75 µA |
| Height tracking (drones, gaming, AR/VR) | 1 | 4 ms | 16 | 0 ms (continuous) | 32x | 8x | 0.2 Pa noise 10 Hz 75 µA |
| Sports, activity tracking | 1 | 4 ms | 1 | 50 ms (pulsed) | 4x | 4x | 0.5 Pa noise 10 Hz 30 µA |
| Home- and Building Automation, HVAC (filter clogging) | 1 | 2 ms | 1 | 1 s (pulsed) | 4x | 4x | 0.7 Pa noise 1 Hz 1.7 µA |

| | | | | | | | |
|---|---|------|---|-------------------|------|------|--|
| Lowest power - barometer, weather station | 0 | 1 ms | 1 | 60 s (pulsed) | 1x | 1x | 1.5 Pa noise 1/60 Hz 0.8 μ A |
| Lowest noise | 1 | 4 ms | 1 | 0 ms (continuous) | 128x | 128x | 0.1 Pa noise 2 Hz |

9.4 Sample communication sequence for common tasks

The following code is a functional example and does not include error checking, so it is not suited for production.

For `Write()` instructions, the first attribute is the register address and the second is the value to be written to that address.

9.4.1 Basic example using single shot measurement mode

```
Write(0x06, 0x08)    // soft reset, equivalent to power-up
Wait(500 us)
// *** configuration: shortest measurement time and one-shot ***
// (default is 2 ms + continuous measurements)
Write(0x06, 0x80)    // enable all registers with bit HP=1
Wait(500us)
Write(0x07, 0x00)    // 1 ms conversion time
Write(0x08, 0x01)    // one-shot operation
Write(0x06, 0x00)    // switch back to ultra-low power mode HP=0
                    // (this saves power if the measurement is triggered later)
Wait(500 us)        // wait a user-defined time until a measurement starts
// *** perform a measurement in ultra-low power mode ***
Write(0x06, 0x13)    // start T+P measurement, ultra-low power, no FIFO
Wait(10 ms)         // wait T+P measurement time (8 ms + margin)
// *** read the data ***
S = Read(0x14)       // check PR & TR in DATA_STAT to confirm that data is ready
If ((S & 3) != 3) {
    Print("Warning: measurement was not complete" ) }
buffer = ReadN(0x17, 5) // read all five data bytes (register 0x17 to 0x1B)
// *** convert, and print the data ***
T = buffer[3] | (buffer[4] << 8)    // = buffer[0] + 256*buffer[1]
P = buffer[0] | (buffer[1] << 8) | (buffer[2] << 16)
Print(P/64.0, "Pa")
Print(T/128.0 - 273.15, "C")
```

9.4.2 Example using continuous mode with FIFO

```
Write(0x06, 0x08)    // soft reset, equivalent to power-up
Wait(500us)
```

```
Write(0x06, 0x80)          // enable all registers with HP bit
Wait(500 us)
Write(0x07, 0x04)          // 1ms measurement time, PT-rate 32
Write(0x09, 0x00)          // OVSP 1X, OVST 1X
Write(0x0B, 0x04)          // interrupt enabled
Write(0x0C, 0x50)          // interrupt on TR and FIFO full
Write(0x06, 0xB3)          // start measurement, P+T, FIFO enabled
// *** Repeat as long as measurements are required ***
    Wait(INT==1)            // Wait until INT hardware pin is high
    S=Read(0x16)            // INT_STAT
    If (S & 0x40) {         // TR flag: temperature ready
        buffer = ReadN(0x1A, 2)          // read TEMP_OUT bytes
        T = buffer[0] | (buffer[1] << 8) // = buffer[0] + 256*buffer[1]
        Print(T/128.0 - 273.15, "C")
    }
    If (S & 0x10) {         // FF flag: FIFO is full
        buffer = ReadN(0x27, 32*3)      // read all data in FIFO
        for(i=0; i<32*3; i=i+3) {
            P = buffer[i] | (buffer[i+1] << 8) | (buffer[i+2] << 16)
            Print(P/64.0, "Pa")
        }
    }
// *** Turn off when measurements are not needed ***
Write(0x06, 0)             //HP=0: put device in ultra-low power mode
```

10 Soldering information

The ENS220 uses an open LGA package. This package can be soldered using a standard reflow process in accordance with IPC/JEDEC J-STD-020E (Figure 31). Devices have been verified against MSL1 storage conditions.

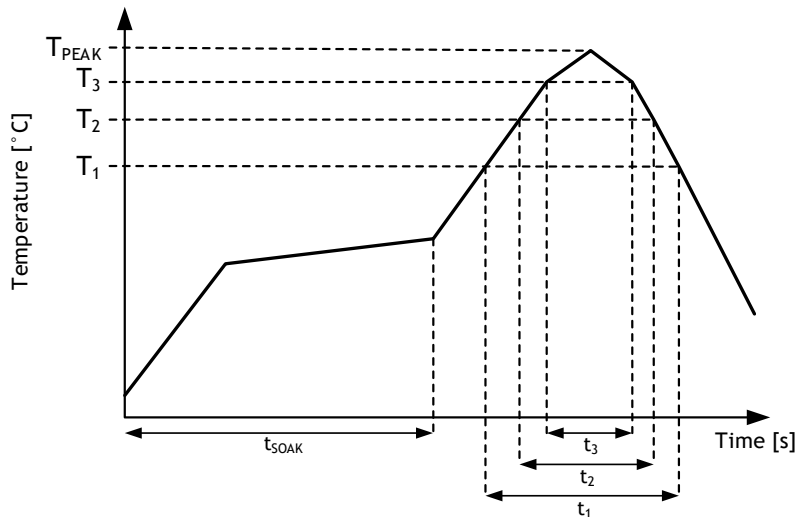


Figure 31: Solder reflow profile graph

The detailed settings for the reflow profile are shown in Table 36.

Table 36: Solder Reflow Profile

| Parameter | Reference | Rate / Unit |
|--|------------|-------------|
| Average temperature gradient in preheating | | 2.5 K/s |
| Soak time | t_{SOAK} | 2..3 min |
| Soak temp range | Ts max | 200 °C |
| | Ts min | 150 °C |
| Time above 217 °C (T1) | t_1 | Max. 60 s |
| Time above 230 °C (T2) | t_2 | Max. 50 s |
| Time above TPEAK -10 °C (T3) | t_3 | Max. 10 s |
| Peak temperature in reflow | T_{PEAK} | 260 °C |
| Temperature gradient in cooling | | Max. -5 K/s |

It is recommended to use a no-clean solder paste. There should not be any board wash processes, to prevent cleaning agents or other liquid materials contacting the sensor area.

11 Package drawings & markings

11.1 Package outline dimensions

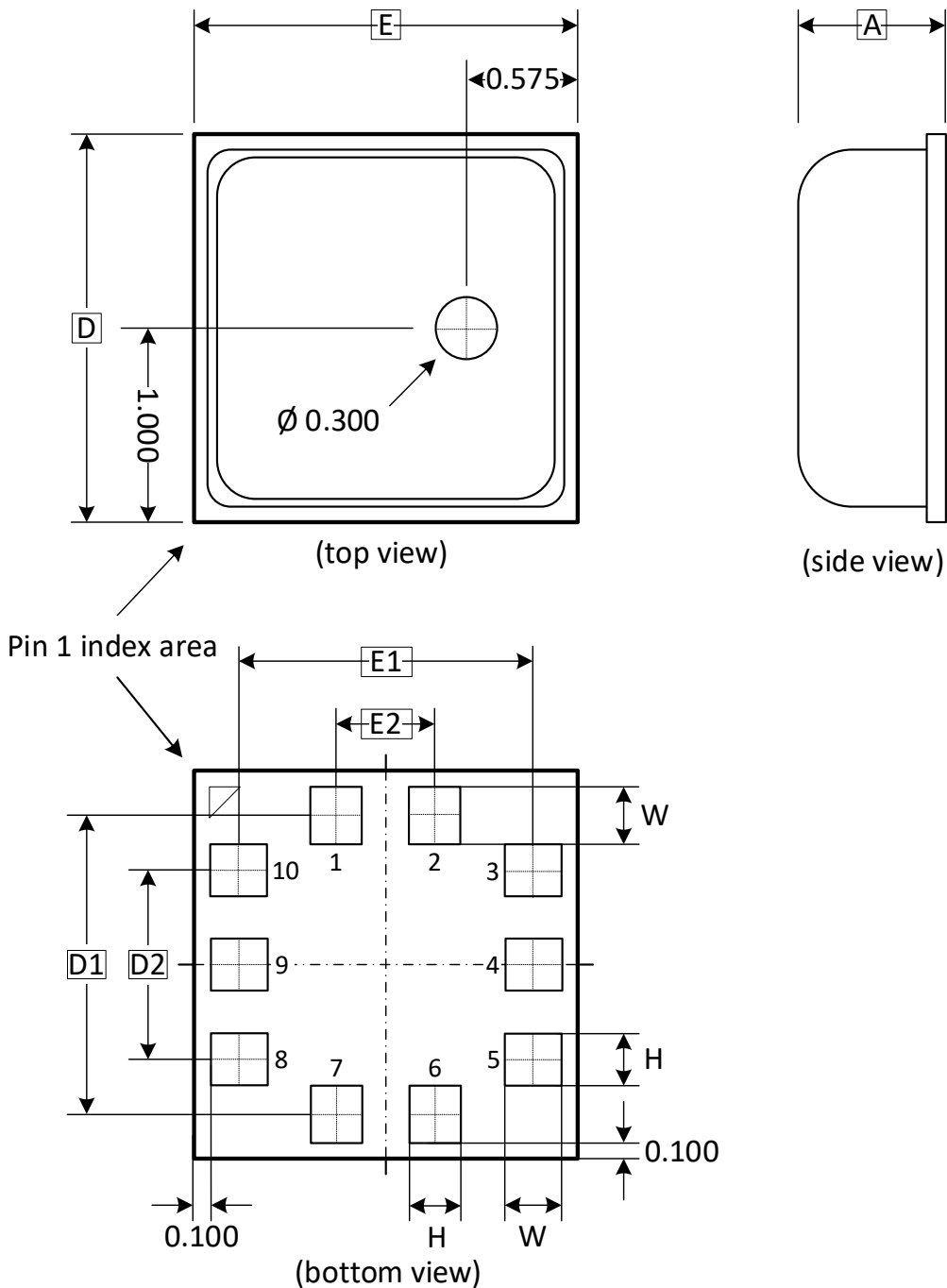


Figure 32: LGA package drawing

Table 37: LGA package dimensions in mm

| Parameter | Symbol | Dimensions | | |
|-----------------------|--------|------------|---------|------|
| | | Min | Nominal | Max |
| Total thickness | A | 0.70 | 0.75 | 0.80 |
| Body Size | D | 1.95 | 2.00 | 2.05 |
| | E | 1.95 | 2.00 | 2.05 |
| Lead Width | W | | 0.275 | |
| Lead Length | H | | 0.250 | |
| Lead Count | n | | 10 | |
| Lead Centre to Centre | D1 | | 1.525 | |
| | D2 | | 1.00 | |
| | E1 | | 1.525 | |
| | E2 | | 0.5 | |

11.2 Landing pattern

SciSense suggests a footprint (land pattern) on the PCB as depicted in Figure 33 (which is identical to the pad pattern in the outline drawing Figure 32). Please find the dimensions in Table 37.

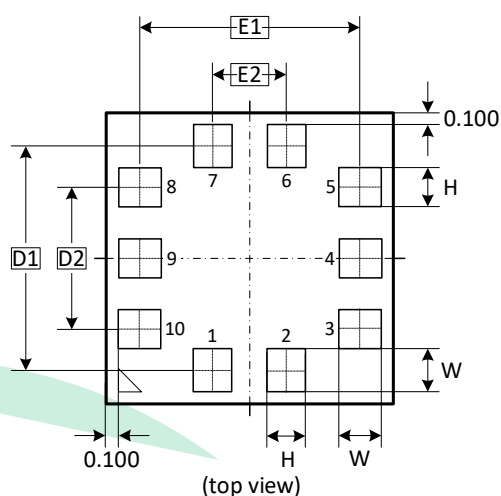


Figure 33: LGA land pattern (top view)

11.3 Device marking

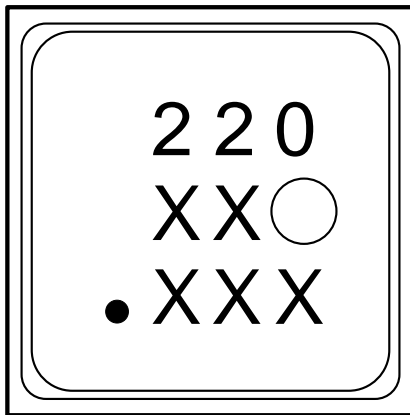


Figure 34: LGA package marking

12 Ordering information

Table 38: Ordering information

| Ordering Code | Material ID | Package | Delivery Form | Delivery Quantity |
|---------------|-------------|------------|----------------|-------------------|
| ENS220S-BLGT | 503700104 | 10-pin LGA | 7" Tape & reel | 3'500 pcs |

13 RoHS Compliance & ScioSense Green Statement

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15 Document status

Table 39: Document status

| Document Status | Product Status | Definition |
|--------------------------|-----------------|---|
| Product Preview | Pre-Development | Information in this datasheet is based on product ideas in the planning phase of development. All specifications are design goals without any warranty and are subject to change without notice. |
| Preliminary Datasheet | Pre-Production | Information in this datasheet is based on products in the design, validation, or qualification phase of development. The performance and parameters shown in this document are preliminary without any warranty and are subject to change without notice. |
| Datasheet | Production | Information in this datasheet is based on products in ramp-up to full production or full production which conform to specifications in accordance with the terms of Sciosense B.V. standard warranty as given in the General Terms of Trade. |
| Datasheet (Discontinued) | Discontinued | Information in this datasheet is based on products which conform to specifications in accordance with the terms of Sciosense B.V. standard warranty as given in the General Terms of Trade, but these products have been superseded and should not be used for new designs. |

16 Revision information

Table 40: Revision history

| Revision | Date | Comment | Page |
|----------|------------|---|------------------------|
| 0.10 | 2023-02-10 | Preliminary Version – Improved functional description, PRESS_OUT description, TEMP_OUT description and examples | 13, 41-43, 46-47 |
| 0.9 | 2023-01-20 | Preliminary Version – Update ordering information & device markings | 51 |
| 0.8 | 2022-12-05 | Preliminary Version – Correct package outline information | 49 |
| 0.7 | 2022-12-01 | Preliminary Version – Update specifications | 7 |
| 0.6 | 2022-11-15 | Preliminary Version – Product launch | All |

Note(s) and/or Footnote(s):

1. Page and figure numbers for the previous version may differ from page and figure numbers in the current revision.
2. Correction of typographical errors is not explicitly mentioned.



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